



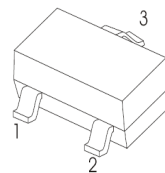
THE DATASHEET OF BC856B

TRANSISTOR PNP

FEATURES

- Ideally suited for automatic insertion
- For Switching and AF Amplifier Applications

SOT-23



1. BASE
2. EMITTER
3. COLLECTOR

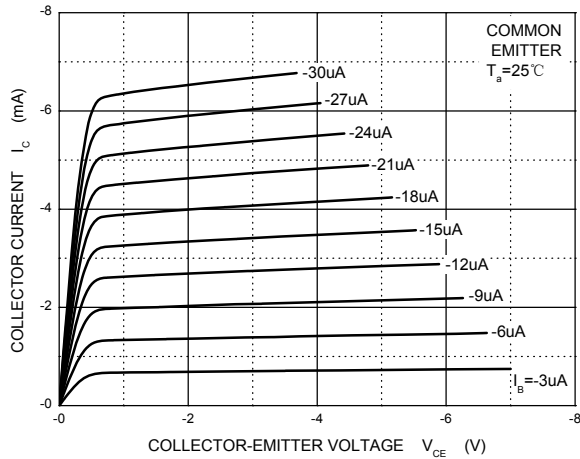
MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage		
	BC856	-80	V
	BC857	-50	
	BC858	-30	
V_{CEO}	Collector-Emitter Voltage		
	BC856	-65	V
	BC857	-45	
	BC858	-30	
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current –Continuous	-0.1	A
P_C	Collector Power Dissipation	200	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	625	$^{\circ}\text{C}/\text{W}$
T_J	Junction Temperature	150	$^{\circ}\text{C}$
T_{stg}	Storage Temperature	-65~+150	$^{\circ}\text{C}$

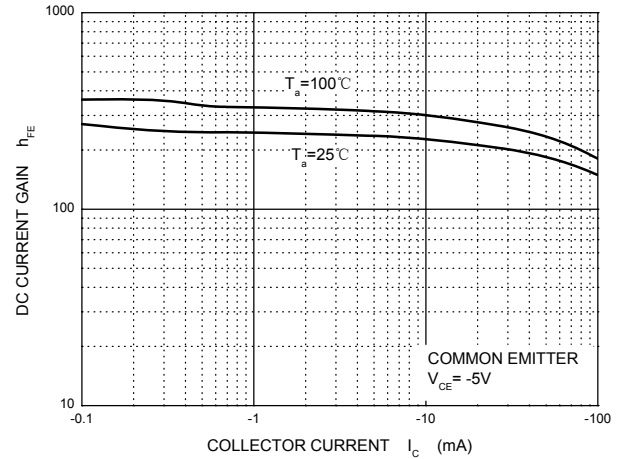
ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown voltage	BC856 BC857 BC858	V_{CBO}	$I_C = -10\mu A, I_E = 0$	-80 -50 -30	V
Collector-emitter breakdown voltage	BC856 BC857 BC858	V_{CEO}	$I_C = -10mA, I_B = 0$	-65 -45 -30	V
Emitter-base breakdown voltage		V_{EBO}	$I_E = -1\mu A, I_C = 0$	-5	V
Collector cut-off current	BC856 BC857 BC858	I_{CBO}	$V_{CB} = -70V, I_E = 0$ $V_{CB} = -45V, I_E = 0$ $V_{CB} = -25V, I_E = 0$	-0.1	μA
Emitter cut-off current		I_{EBO}	$V_{EB} = -5V, I_C = 0$	-0.1	μA
DC current gain	BC856A, 857A, 858A BC856B, 857B, 858B BC857C, BC858C	h_{FE}	$V_{CE} = -5V, I_C = -2mA$	125 220 420	250 475 800
Collector-emitter saturation voltage		$V_{CE(sat)}$	$I_C = -100mA, I_B = -5mA$	-0.5	V
Base-emitter saturation voltage		$V_{BE(sat)}$	$I_C = -100mA, I_B = -5mA$	-1.1	V
Transition frequency		f_T	$V_{CE} = -5V, I_C = -10mA$ $f = 100MHz$	100	MHz
Collector capacitance		C_{ob}	$V_{CB} = -10V, f = 1MHz$	4.5	pF

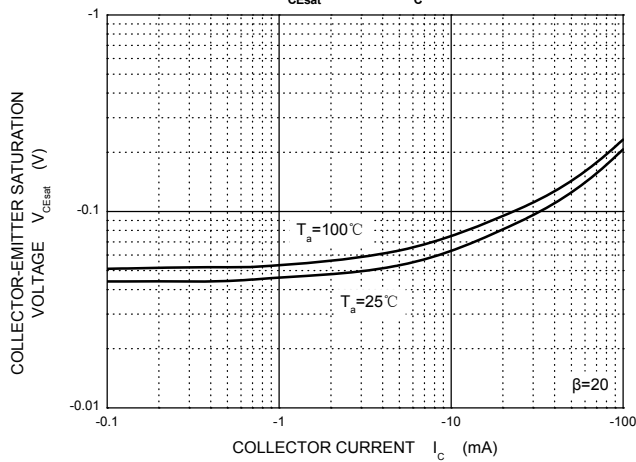
Static Characteristic



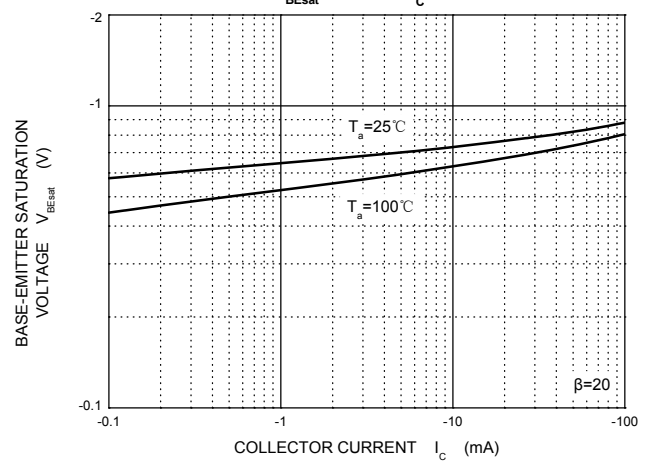
h_{FE} — I_c



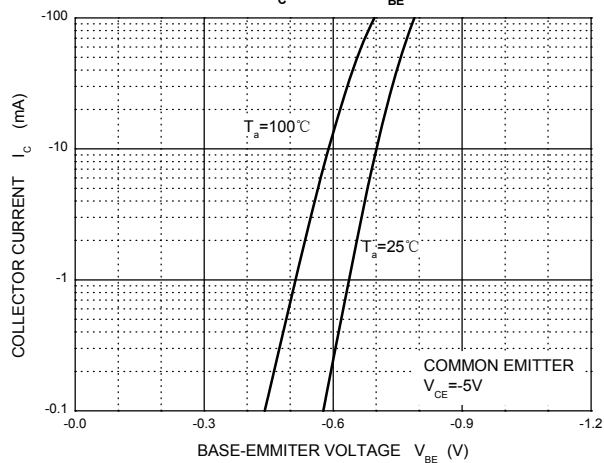
V_{CEsat} — I_c



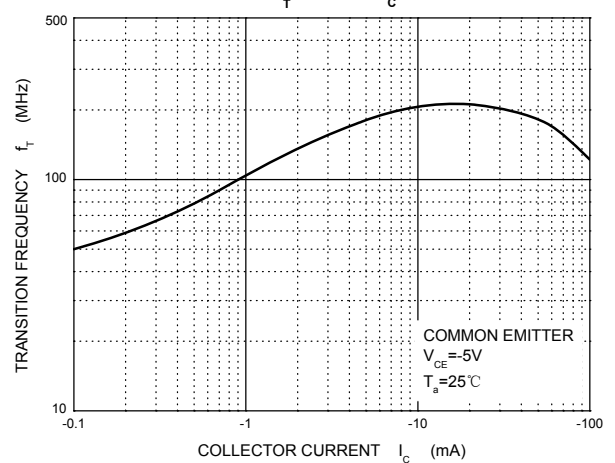
V_{BEsat} — I_c



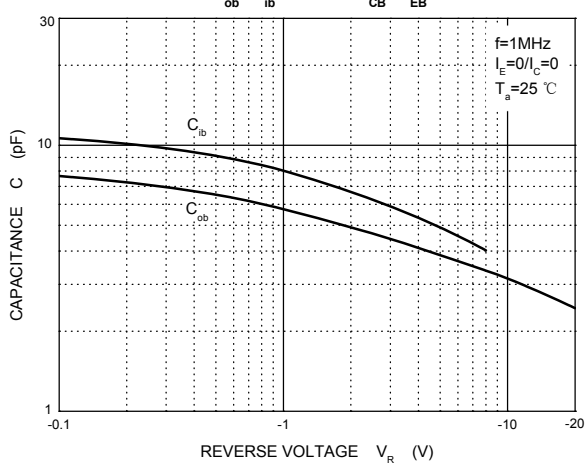
I_c — V_{BE}



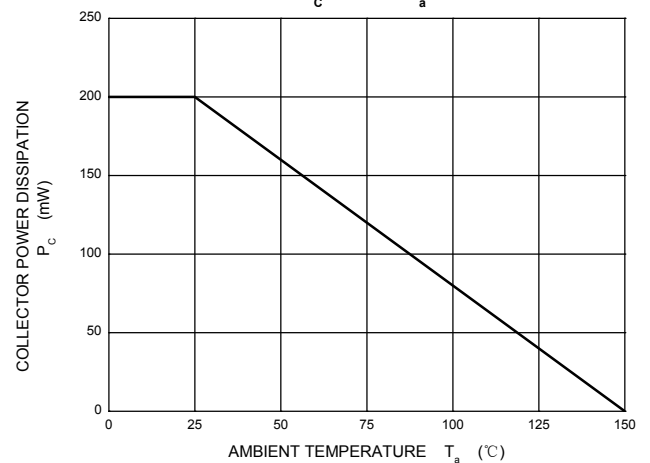
f_T — I_c

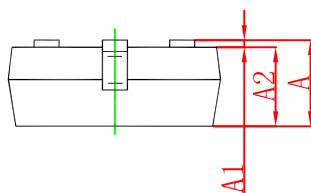
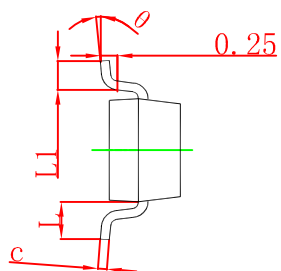
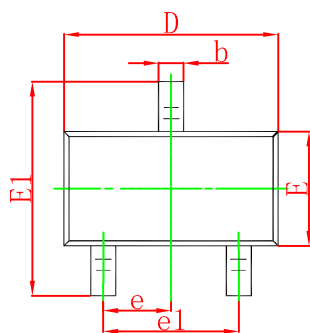


C_{ob}/C_{ib} — V_{CB}/V_{EB}



P_c — T_a





Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

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- ✓ Cost Control Management
- ✓ Shortage Management
- ✓ Alternative Solution
- ✓ Excess Inventory Management